2SP0320T2E0-FF650R17IE4
2SP0320T2E0C-FF650R17IE4
Data Sheet

Compact, high-performance, plug-and-play dual-channel IGBT driver based on SCALE™-2 technology for individual and parallel-connected modules in 2-level, 3-level and multilevel converter topologies

Abstract

The SCALE™-2 plug-and-play driver 2SP0320T2E0-FF650R17IE4 / 2SP0320T2E0C-FF650R17IE4 (Coated version using ELPEGUARD SL 1307 FLZ/2 from Lackwerke Peters) is a compact dual-channel intelligent gate driver designed for Infineon's PrimePACK™ IGBTs FF650R17IE4. The driver features an electrical interface with a built-in DC/DC power supply.

For drivers adapted to other types of high-power and high-voltage IGBT modules, refer to

www.power.com/gate-driver/go/plug-and-play

Features

- ✓ Plug-and-play solution
- ✓ Allows parallel connection of IGBT modules
- ✓ For 2-level, 3-level and multilevel topologies
- ✓ Shortens application development time
- ✓ Extremely reliable; long service life
- ✓ Built-in DC/DC power supply
- ✓ 20-pin flat cable interface
- ✓ Duty cycle 0... 100%
- ✓ Active clamping of V_{ce} at turn-off
- ✓ IGBT short-circuit protection
- ✓ Monitoring of supply voltage
- ✓ Safe isolation to EN 50178
- ✓ UL compliant
- ✓ Lead-free
- ✓ Suitable for FF650R17IE4

Applications

- ✓ Wind-power converters
- ✓ Industrial drives
- ✓ UPS
- ✓ Power-factor correctors
- ✓ Traction
- ✓ Railroad power supplies
- ✓ Welding
- ✓ SMPS
- ✓ Radiology and laser technology
- ✓ Research
- ✓ and many others

Data Sheet

Safety Notice!

The data contained in this data sheet is intended exclusively for technically trained staff. Handling all high-voltage equipment involves risk to life. Strict compliance with the respective safety regulations is mandatory!

Any handling of electronic devices is subject to the general specifications for protecting electrostatic-sensitive devices according to international standard IEC 60747-1, Chapter IX or European standard EN 100015 (i.e. the workplace, tools, etc. must comply with these standards). Otherwise, this product may be damaged.

Important Product Documentation

This data sheet contains only product-specific data. For a detailed description, must-read application notes and common data that apply to the whole series, please refer to "Description & Application Manual for 2SP0320T SCALE-2 IGBT Drivers" on www.power.com/gate-driver/go/2SP0320.

When applying SCALE-2 plug-and-play drivers, please note that these drivers are specifically adapted to a particular type of IGBT module. Therefore, the type designation of SCALE-2 plug-and-play drivers also includes the type designation of the corresponding IGBT module. These drivers are not valid for IGBT modules other than those specified. Incorrect use may result in failure.

Mechanical Dimensions

Dimensions: Refer to the relevant "Description and Application Manual"

Mounting principle: Connected to IGBT module with screws

Absolute Maximum Ratings

Parameter	Remarks	Min	Max	Unit
Supply voltage V_{DC}	VDC to GND	0	16	V
Supply voltage V_{CC}	VCC to GND (Note 1)	0	16	V
Logic input and output voltages	To GND	-0.5	VCC+0.5	V
SO_x current	Fault condition, total current		20	mA
Gate peak current I_{out}	Note 2	-20	+20	A
Average supply current I_{DC}	Note 16		600	mA
Output power per gate	Ambient temperature <70°C (Note 3)		3	W
	Ambient temperature 85°C (Note 3)		2	W
Switching frequency f			20	kHz
Test voltage (50Hz/1min.)	Primary to secondary (Note 19)		5000	$V_{AC(eff)}$
	Secondary to secondary (Note 19)		4000	$V_{AC(eff)}$
DC-link voltage	Note 4		1200	V
|dV/dt|	Rate of change of input to output voltage		50	kV/µs
Operating voltage	Primary/secondary, secondary/secondary		1700	V_{peak}
Operating temperature		-40	85	°C
Storage temperature	Note 22	-40	50	°C
Surface temperature	Only 2SP0320T2E0C-FF650R17IE4 (Note 23)		125	°C

Recommended Operating Conditions

Power Supply	Remarks	Min	Typ	Max	Unit
Supply voltage V_{DC}	To GND (Note 1)	14.5	15	15.5	V
Supply voltage V_{CC}	To GND (Note 1)	14.5	15	15.5	V
Resistance from TB to GND	Blocking time ≠ 0, ext. value	128		∞	kΩ
SO_x current	Fault condition, 3.3V logic			4	mA

Electrical Characteristics

Power Supply	Remarks	Min	Typ	Max	Unit
Supply current I_{DC}	Without load		37		mA
Efficiency η	Internal DC/DC converter		85		%
Supply current I_{CC}	Without load		19		mA
Coupling capacitance C_{io}	Primary side to secondary side, total, per channel		22		pF
Power Supply Monitoring	**Remarks**	**Min**	**Typ**	**Max**	**Unit**
Supply threshold V_{CC}	Primary side, clear fault	11.9	12.6	13.3	V
	Primary side, set fault (Note 5)	11.3	12.0	12.7	V
Monitoring hysteresis	Primary side, set/clear fault	0.35			V
Supply threshold V_{isox}-V_{eex}	Secondary side, clear fault	12.1	12.6	13.1	V
	Secondary side, set fault (Note 20)	11.5	12.0	12.5	V
Monitoring hysteresis	Secondary side, set/clear fault	0.35			V
Supply threshold V_{eex}-V_{COMx}	Secondary side, clear fault	5	5.15	5.3	V
	Secondary side, set fault (Note 20)	4.7	4.85	5	V
Monitoring hysteresis	Secondary side, set/clear fault	0.15			V
Logic Inputs and Outputs	**Remarks**	**Min**	**Typ**	**Max**	**Unit**
Input impedance	V(INx) > 3V (Note 6)	3.5	4.1	4.6	kΩ
Turn-on threshold	V(INx) (Note 7)		2.6		V
Turn-off threshold	V(INx) (Note 7)		1.3		V
SOx output voltage	Fault condition, I(SOx) < 8mA			0.7	V
Short-circuit Protection	**Remarks**	**Min**	**Typ**	**Max**	**Unit**
Vce-monitoring threshold	Between auxiliary terminals		10.2		V
Response time	DC-link voltage > 550V (Note 8)		6.9		µs
Delay to IGBT turn-off	After the response time (Note 9)		1.4		µs
Blocking time	After fault (Note 10)		90		ms

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Timing Characteristics	**Remarks**	**Min**	**Typ**	**Max**	**Unit**
Turn-on delay $t_{d(on)}$	Note 11		80		ns
Turn-off delay $t_{d(off)}$	Note 11		90		ns
Jitter of turn-on delay	Note 12		±2		ns
Jitter of turn-off delay	Note 12		±2		ns
Output rise time $t_{r(out)}$	G_x to E_x (Note 13)		7		ns
Output fall time $t_{f(out)}$	G_x to E_x (Note 13)		25		ns
Dead time between outputs	Half-bridge mode (Note 14)		3		µs
Jitter of dead time	Half-bridge mode		±100		ns
Transmission delay of fault state	Note 15		450		ns
Outputs	**Remarks**	**Min**	**Typ**	**Max**	**Unit**
Turn-on gate resistor $R_{g(on)}$	Note 17		1.9		Ω
Turn-off gate resistor $R_{g(off)}$	Note 17		3.3		Ω
Gate voltage at turn-on			15		V
Gate-voltage at turn-off	P = 0W		-10.4		V
	P = 0.3W		-10.2		V
	P = 2.1W		-9.7		V
	P = 3W		-9.6		V
Gate resistance to COMx			4.7		kΩ
dV/dt Feedback	**Remarks**		**Implementation**		
dV/dt feedback	Note 18		No		
Electrical Isolation	**Remarks**	**Min**	**Typ**	**Max**	**Unit**
Test voltage (50Hz/1s)	Primary to secondary side (Note 19)	5000	5050	5100	V_{eff}
	Secondary to secondary side (Note 19)	4000	4050	4100	V_{eff}
Partial discharge extinction volt.	Primary to secondary side (Note 21)	1768			V_{peak}
	Secondary to secondary side (Note 21)	1700			V_{peak}
Creepage distance	Primary to secondary side	20			mm
	Secondary to secondary side	17			mm

All data refer to +25°C and V_{CC} = V_{DC} = 15V unless otherwise specified

Footnotes to the Key Data

1) Both supply voltages V_{DC} and V_{CC} should be applied in parallel.
2) The gate current is limited by the gate resistors located on the driver.
3) If the specified value is exceeded, this indicates a driver overload. It should be noted that the driver is not protected against overload. From 70°C to 85°C, the maximum permissible output power can be linearly interpolated from the given data.
4) This limit is due to active clamping. Refer to "Description & Application Manual for 2SP0320T SCALE-2 IGBT Drivers".
5) Undervoltage monitoring of the primary-side supply voltage (VCC to GND). If the voltage drops below this limit, a fault is transmitted to the corresponding output(s) and the IGBTs are switched off.
6) The input impedance can be modified to values < 18 kΩ (customer-specific solution).
7) Turn-on and turn-off threshold values can be increased (customer-specific solution).
8) The resulting pulse width of the direct output of the gate drive unit for short-circuit type I (excluding the delay of the gate resistors) is the sum of response time plus delay to IGBT turn-off.
9) The turn-off event of the IGBT is delayed by the specified time after the response time.
10) Factory set value. The blocking time can be reduced with an external resistor. Refer to "Description & Application Manual for 2SP0320T SCALE-2 IGBT Drivers".
11) Measured from the transition of the turn-on or turn-off command at the driver input to direct output of the gate drive unit (excluding the delay of the gate resistors).
12) Jitter measurements are performed with input signals INx switching between 0V and 15V referred to GND, with a corresponding rise time and fall time of 8ns.
13) Refers to the direct output of the gate drive unit (excluding the delay of the gate resistors).
14) Note that the dead time may vary from sample to sample. A tolerance of approximately ±20% may be expected. If higher timing precisions are required, Power Integrations recommends using direct mode and generating the dead time externally.
15) Transmission delay of the fault state from the secondary side to the primary status outputs.
16) If the specified value is exceeded, this indicates a driver overload. It should be noted that the driver is not protected against overload.
17) The gate resistors can be leaded or surface mounted. Power Integrations reserves the right to determine which type will be used. Typically, higher quantities will be produced with SMD resistors and small quantities with leaded resistors.
18) A dV/dt feedback can optionally be implemented in order to reduce the rate of rise of the collector emitter voltage of the IGBTs at turn-off (customer-specific solution).
19) HiPot testing (= dielectric testing) must generally be restricted to suitable components. This gate driver is suited for HiPot testing. Nevertheless, it is strongly recommended to limit the testing time to 1s slots as stipulated by EN 50178. Excessive HiPot testing at voltages much higher than $1200V_{AC(eff)}$ may lead to insulation degradation. No degradation has been observed over 1min. testing at $5000V_{AC(eff)}$. The transformer of every production sample shipped to customers has undergone 100% testing at the given value for 1s.
20) Undervoltage monitoring of the secondary-side supply voltage (Visox to Veex and Veex to COMx which correspond with the approximate turn-on and turn-off gate-emitter voltages). If the corresponding voltage drops below this limit, the IGBT is switched off and a fault is transmitted to the corresponding output.
21) Partial discharge measurement is performed in accordance with IEC 60270 and isolation coordination specified in EN 50178. The partial discharge extinction voltage between primary and either secondary side is coordinated for safe isolation to EN 50178.
22) The storage temperature inside the original package (1) or in case the coating material of coated products may touch external parts (2) must be limited to the given value. Otherwise, it is limited to 90°C.
23) The component surface temperature, which may strongly vary depending on the operating condition, must be limited to the given value for coated driver versions to ensure long-term reliability of the coating material.

RoHS Statement

On the basis of Annexes II and III of European Directive 2011/65/EC of 08 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (RoHS), we hereby state that the products described in this datasheet do not contain lead (Pb), mercury (Hg), hexavalent chromium (Cr VI), cadmium (Cd), polibrometo of biphenyl (PBB) or polibrometo diphenyl ether (PBDE) in concentrations exceeding the restrictions set forth in Annex II of 2011/65/EC with due consideration of the applicable exemptions as listed in Annex III of 2011/65/EC.

Legal Disclaimer

The statements, technical information and recommendations contained herein are believed to be accurate as of the date hereof. All parameters, numbers, values and other technical data included in the technical information were calculated and determined to our best knowledge in accordance with the relevant technical norms (if any). They may base on assumptions or operational conditions that do not necessarily apply in general. We exclude any representation or warranty, express or implied, in relation to the accuracy or completeness of the statements, technical information and recommendations contained herein. No responsibility is accepted for the accuracy or sufficiency of any of the statements, technical information, recommendations or opinions communicated and any liability for any direct, indirect or consequential loss or damage suffered by any person arising therefrom is expressly disclaimed.

Ordering Information

Our international terms and conditions of sale apply.

Interface	Power Integrations Driver Type #	Related IGBT
Electrical Interface [1)]	2SP0320T2E0-FF650R17IE4	FF650R17IE4
Electrical Interface [2)]	2SP0320T2E0C-FF650R17IE4	FF650R17IE4

[1)] RoHS version with improved EMI capability
[2)] RoHS version with improved EMI capability and conformal coating

Product home page: www.power.com/gate-driver/go/2SP0320

Refer to www.power.com/gate-driver/go/nomenclature for information on driver nomenclature

Information about Other Products

For other drivers, evaluation systems product documentation and application support

Please click: www.power.com/gate-driver

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